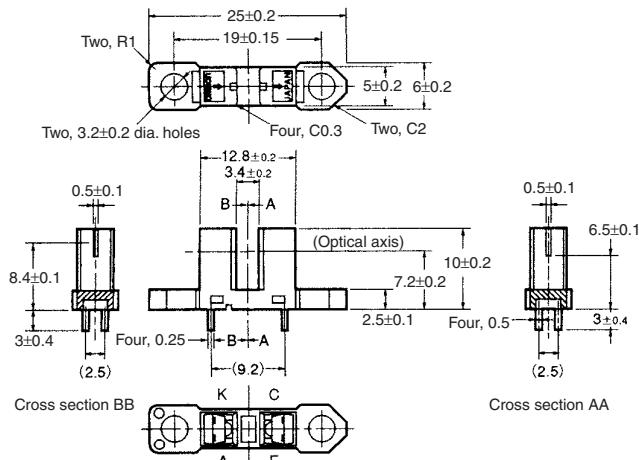


# Photomicrosensor (Transmissive) EE-SX1088

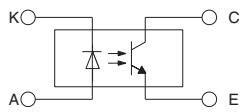
**⚠ Be sure to read *Precautions* on page 25.**

## ■ Dimensions

Note: All units are in millimeters unless otherwise indicated.



Internal Circuit



Unless otherwise specified, the tolerances are as shown below.

Dimensions	Tolerance
3 mm max.	±0.3
3 < mm ≤ 6	±0.375
6 < mm ≤ 10	±0.45
10 < mm ≤ 18	±0.55
18 < mm ≤ 30	±0.65

Terminal No.	Name
A	Anode
K	Cathode
C	Collector
E	Emitter

## ■ Features

- General-purpose model with a 3.4-mm-wide slot.
- Mounts to PCBs or connects to connectors.
- High resolution with a 0.5-mm-wide aperture.
- OMRON's XK8-series Connectors can be connected without soldering. Contact your OMRON representative for information on obtaining XK8-series Connectors.

## ■ Absolute Maximum Ratings ( $T_a = 25^\circ\text{C}$ )

Item	Symbol	Rated value
Emitter	Forward current	$I_F$ 50 mA (see note 1)
	Pulse forward current	$I_{FP}$ 1 A (see note 2)
	Reverse voltage	$V_R$ 4 V
Detector	Collector-Emitter voltage	$V_{CEO}$ 30 V
	Emitter-Collector voltage	$V_{ECO}$ ---
	Collector current	$I_C$ 20 mA
	Collector dissipation	$P_C$ 100 mW (see note 1)
	Operating	$T_{opr}$ -25°C to 85°C
Ambient temperature	Storage	$T_{stg}$ -30°C to 100°C
	Soldering temperature	$T_{sol}$ 260°C (see note 3)

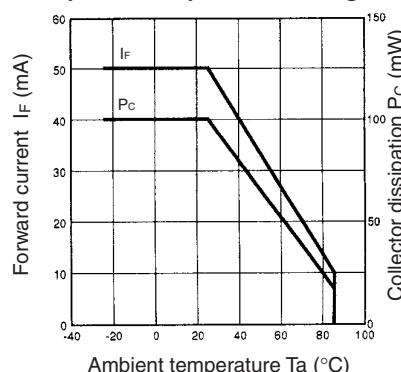
- Note: 1. Refer to the temperature rating chart if the ambient temperature exceeds 25°C.  
 2. The pulse width is 10  $\mu\text{s}$  maximum with a frequency of 100 Hz.  
 3. Complete soldering within 10 seconds.

## ■ Electrical and Optical Characteristics ( $T_a = 25^\circ\text{C}$ )

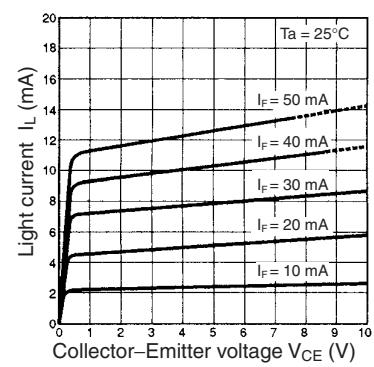
Item	Symbol	Value	Condition
Emitter	Forward voltage	$V_F$ 1.2 V typ., 1.5 V max.	$I_F = 30 \text{ mA}$
	Reverse current	$I_R$ 0.01 $\mu\text{A}$ typ., 10 $\mu\text{A}$ max.	$V_R = 4 \text{ V}$
	Peak emission wavelength	$\lambda_P$ 940 nm typ.	$I_F = 20 \text{ mA}$
Detector	Light current	$I_L$ 0.5 mA min., 14 mA max.	$I_F = 20 \text{ mA}, V_{CE} = 10 \text{ V}$
	Dark current	$I_D$ 2 nA typ., 200 nA max.	$V_{CE} = 10 \text{ V}, 0 \text{ lux}$
	Leakage current	$I_{LEAK}$ ---	---
	Collector-Emitter saturated voltage	$V_{CE}(\text{sat})$ 0.15 V typ., 0.4 V max.	$I_F = 20 \text{ mA}, I_L = 0.1 \text{ mA}$
	Peak spectral sensitivity wavelength	$\lambda_P$ 850 nm typ.	$V_{CE} = 10 \text{ V}$
Rising time	tr	4 $\mu\text{s}$ typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 5 \text{ mA}$
Falling time	tf	4 $\mu\text{s}$ typ.	$V_{CC} = 5 \text{ V}, R_L = 100 \Omega, I_L = 5 \text{ mA}$

## ■ Engineering Data

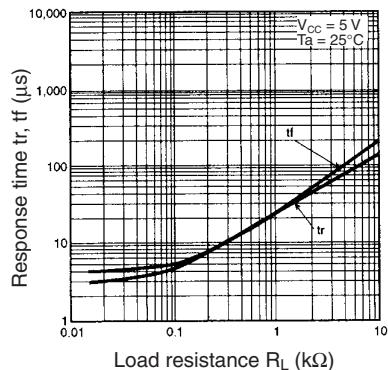
**Forward Current vs. Collector Dissipation Temperature Rating**



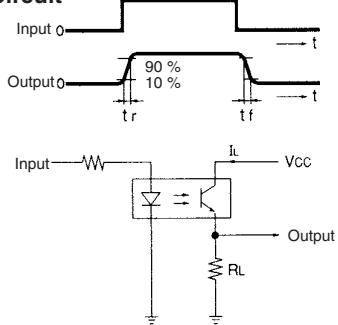
**Light Current vs. Collector-Emitter Voltage Characteristics (Typical)**



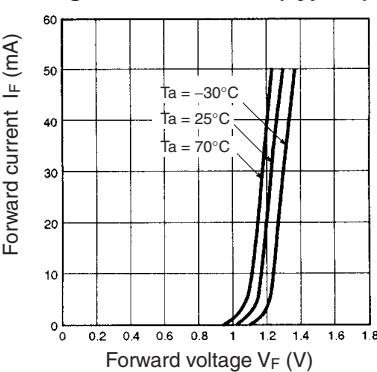
**Response Time vs. Load Resistance Characteristics (Typical)**



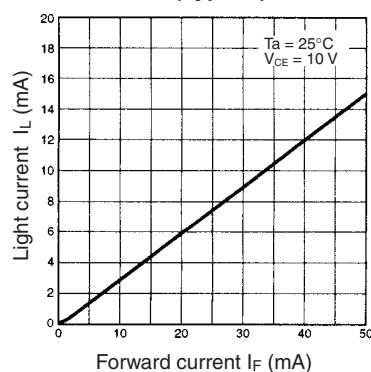
**Response Time Measurement Circuit**



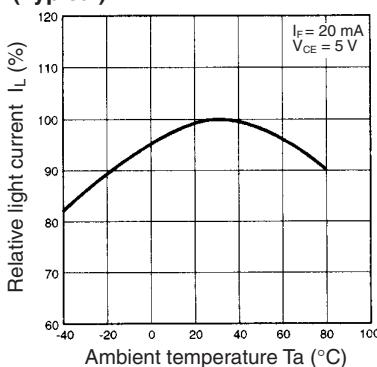
**Forward Current vs. Forward Voltage Characteristics (Typical)**



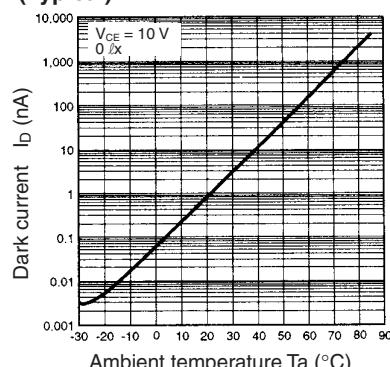
**Light Current vs. Forward Current Characteristics (Typical)**



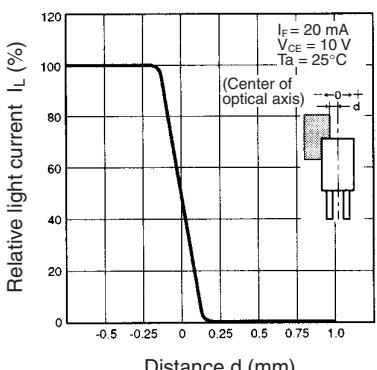
**Relative Light Current vs. Ambient Temperature Characteristics (Typical)**



**Dark Current vs. Ambient Temperature Characteristics (Typical)**



**Sensing Position Characteristics (Typical)**



**Sensing Position Characteristics (Typical)**

